

# INTERNATIONAL RECTIFIER

## 1N3288, 1N3288A SERIES 100 Amp Avg Silicon Rectifier Diodes

### Major Ratings and Characteristics

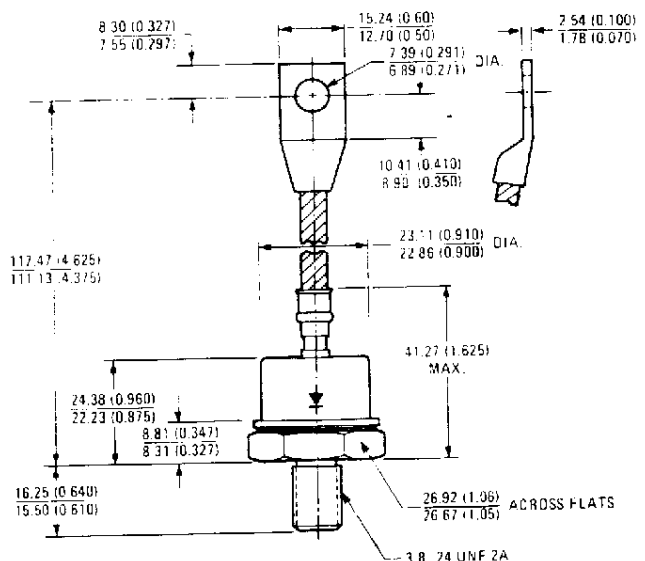
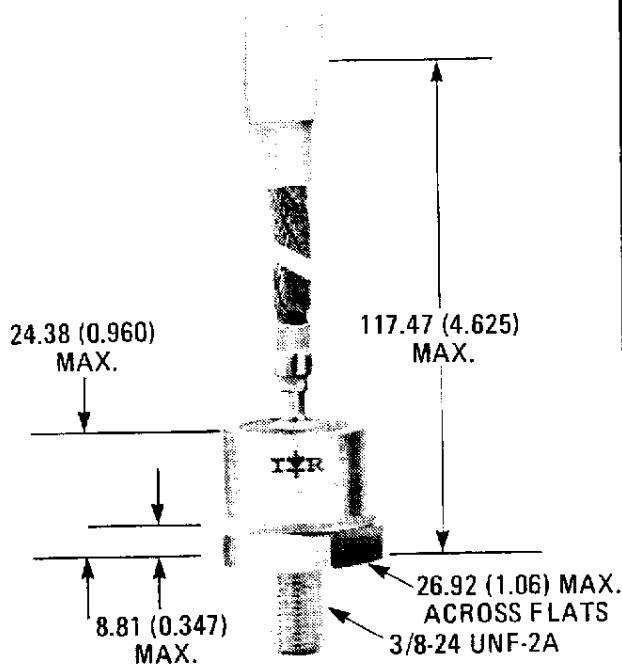
	1N3288	1N3288A	Units
$I_{F(AV)}$	100*	100*	A
@ Max. $T_C$	130	130	$^{\circ}C$
$I_{FSM}$ @ 50 Hz	1550	2200	A
@ 60 Hz	1600*	2300*	
$I^2t$ @ 50 Hz	11,500	24,000	$A^2s$
@ 60 Hz	10,500	22,000	
$I^2\sqrt{t}$	165,000	340,000	$A^2\sqrt{s}$
$V_{RRM}$ Range	100 -1200	100 -1200	V

\*JEDEC registered values.

### Description and Features

- Reverse voltage ratings up to 1200 volts
- High surge rating series (2,300A)
- DO-8 hermetically sealed package
- Superior reliability under extreme conditions
- Can be supplied to meet stringent military, aerospace and other high-reliability requirements

### CASE STYLE AND DIMENSIONS



Conforms to JEDEC outline DO-205AA (DO-8) (IR B-15)

All Dimensions in Millimeters and (Inches)

VOLTAGE RATINGS

	V <sub>RRM</sub> – Max. Repetitive Peak Reverse Voltage (V)	V <sub>RSM</sub> – Max. Non-repetitive Peak Reverse Voltage (V)	V <sub>R</sub> – Max. Direct Reverse Voltage (V)	I <sub>RRM</sub> – Max. Peak Reverse Current Max. Rated I <sub>F(AV)</sub> and V <sub>RRM</sub> 1 Phase Operation (mA)
Part Number ①	T <sub>C</sub> = -40°C to 200°C ②	T <sub>C</sub> = 25°C to 200°C	T <sub>C</sub> = -40°C to 200°C ②	T <sub>C</sub> = 130°C
1N3288 1N3288A	100*	200*	100*	24*
1N3289 1N3289A	200*	300*	200*	24*
1N3290 1N3290A	300*	400*	300*	24*
1N3291 1N3291A	400*	525*	400*	24*
1N3292 1N3292B	500*	650*	500*	21*
1N3293 1N3293A	600*	800*	600*	17*
1N3294 1N3294A	800*	1050*	800*	13*
1N3295 1N3295A	1000*	1300*	1000*	11*
1N3296 1N3296A	1200*	1600*	1200*	9*

① Basic number indicates cathode-to-case. For anode-to-case, add "R" to part number, e.g., 1N3291RA

ELECTRICAL SPECIFICATIONS

	1N3288	1N3288A ③	Units	Conditions	
I <sub>F(AV)</sub> Max. average forward current	100*	100*	A	180° sinusoidal conduction. Max. T <sub>C</sub> = 130°C*	
I <sub>FSM</sub> Max. peak one-cycle non-repetitive surge current	1550	2200	A	Half cycle 50 Hz sine wave or 6 ms rectangular pulse Following any rated load condition and with rated V <sub>RRM</sub> applied.	
	1600	2300			
	1800	2600		Half cycle 50 Hz sine wave or 6 ms rectangular pulse Following any rated load condition and with V <sub>RRM</sub> applied following surge = 0.	
	1900	2750			
I <sup>2</sup> t Max. I <sup>2</sup> t for fusing	11,500	24,000	A <sup>2</sup> s	t = 10 ms With rated V <sub>RRM</sub> applied following surge, initial T <sub>J</sub> = 200°C	
	10,500	22,000			
	Max. I <sup>2</sup> t for individual device fusing	16,500		34,000	t = 10 ms With V <sub>RRM</sub> = 0 following surge, initial T <sub>J</sub> = 200°C
		15,000		31,000	
I <sup>2</sup> √t Max. I <sup>2</sup> √t for individual device ④ fusing	165,000	340,000	A <sup>2</sup> √s	t = 0.1 to 10 ms, V <sub>RRM</sub> = 0 following surge.	
V <sub>FM</sub> Max. peak forward voltage	1.5*	1.5*	V	I <sub>F(AV)</sub> = 100A (314A peak), T <sub>C</sub> = 130°C	

THERMAL-MECHANICAL SPECIFICATIONS

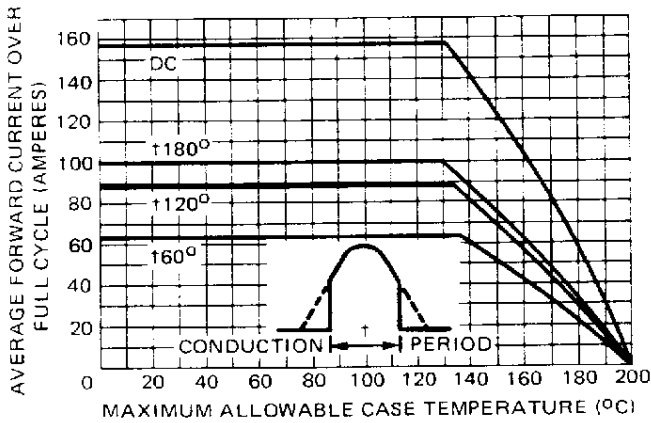
T <sub>C</sub> Max. operating case temperature range	-40° to 200° ②	°C	1N3292B: -65° to 200°C
T <sub>stg</sub> Max. storage temperature range	-40° to 200° ①	°C	1N3292B: -65° to 200°C
R <sub>thJC</sub> Max. internal thermal resistance, junction-to-case	0.4*	deg C/W	DC operation.
R <sub>thCS</sub> Thermal resistance, case-to-sink	0.1	deg C/W	Mounting surface flat, smooth, and greased.
T Mounting torque	11.3-14.1 (100-125)	N · m (lbf-in)	Non-lubricated threads
wt Approximate weight	71 (2.5)	g (oz)	
Case style	DO-205AA (DO-8) (IR B-15)		JEDEC

\*JEDEC registered values.

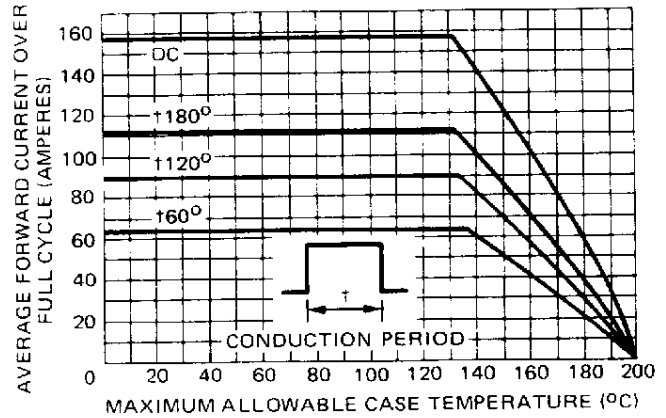
② Min. T<sub>C</sub> = -65°C for 1N3292B only.

④ I<sup>2</sup>t for time t<sub>x</sub> = I<sup>2</sup>√t · √t<sub>x</sub>.

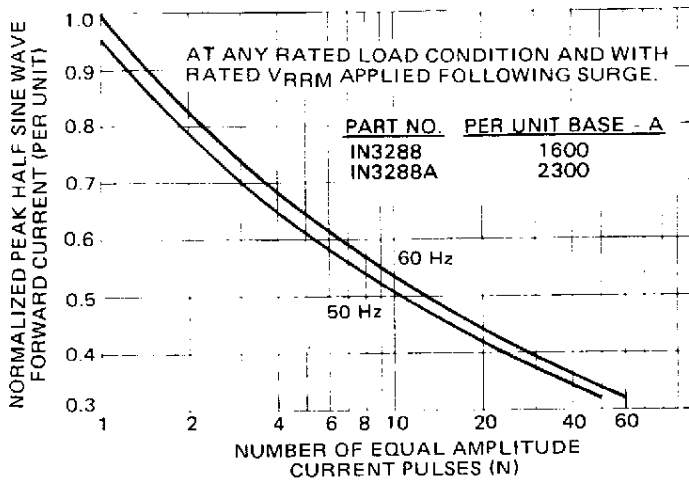
③ Applies to 1N3292B.



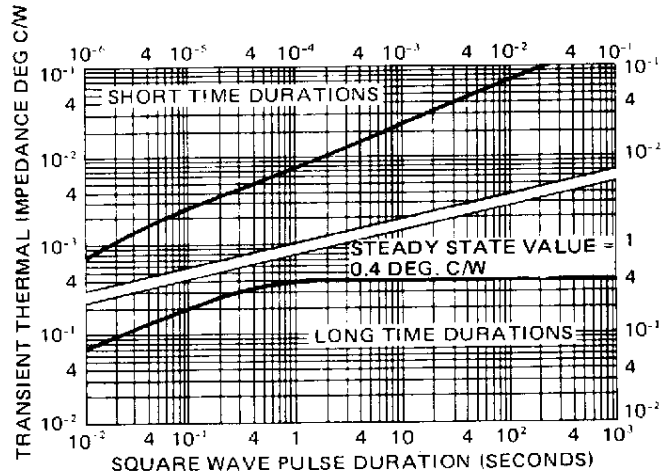
**Fig. 1 – Average Forward Current Vs Case Temperature (Sinusoidal Current Waveform)**



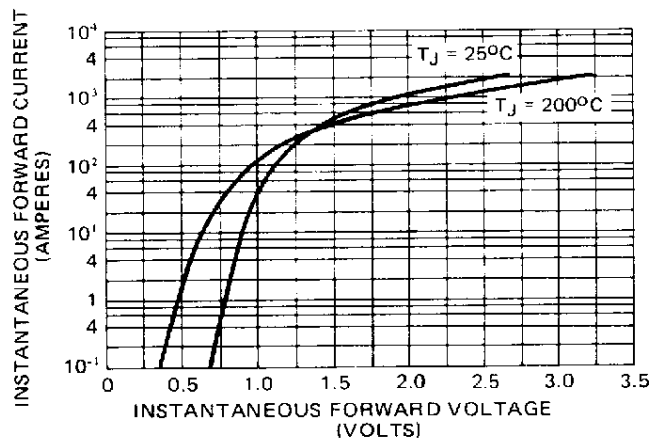
**Fig. 2 – Average Forward Current Vs Case Temperature (Rectangular Current Waveform)**



**Fig. 3 – Maximum Non-Repetitive Normalized Surge Current Vs. Number of Current Pulses**



**Fig. 4 – Maximum Transient Thermal Impedance, Junction-to-Case, Vs. Pulse Duration**



**Fig. 5 – Maximum Forward Voltage Vs Forward Current**

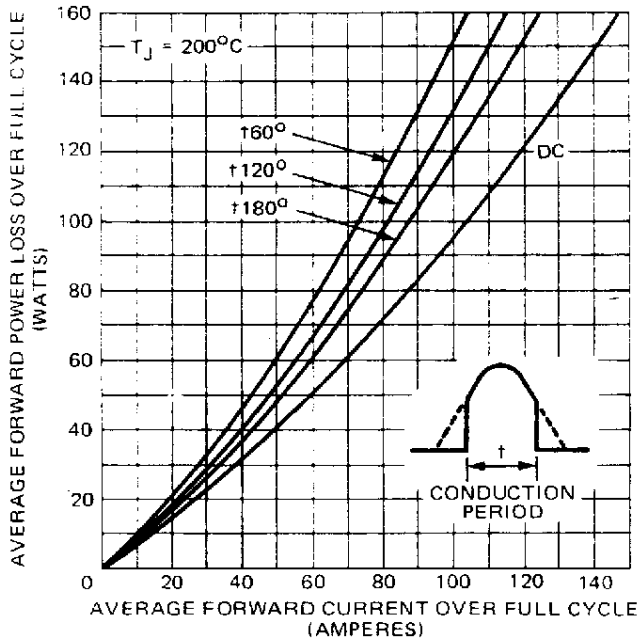


Fig. 6 — Maximum Forward Power Loss Vs Low Level Forward Current (Sinusoidal Current Waveform)

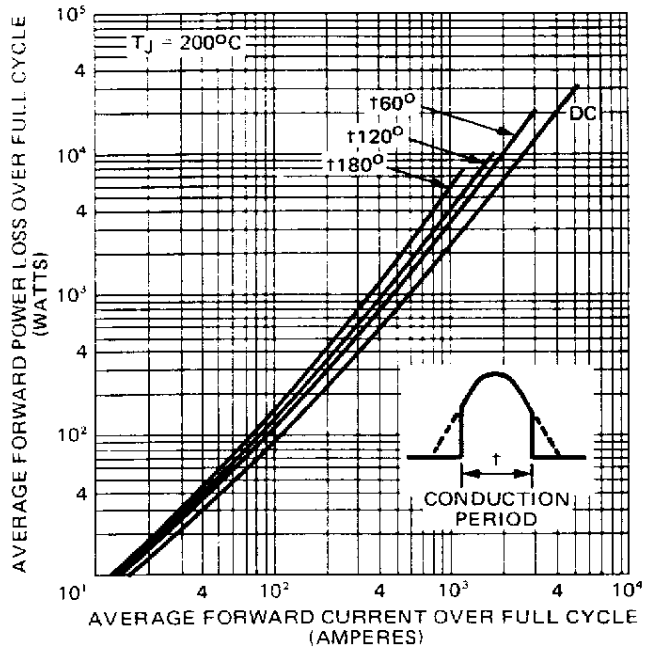


Fig. 7 — Maximum Forward Power Loss Vs High Level Forward Current (Sinusoidal Current Waveform)

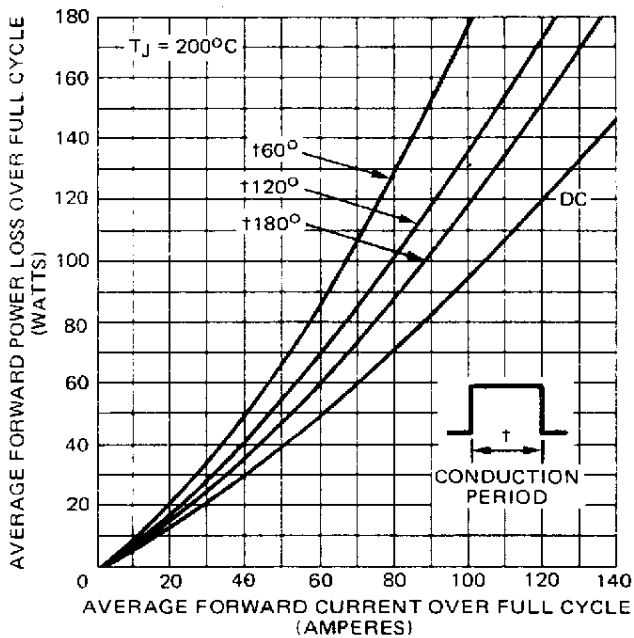


Fig. 8 — Maximum Forward Power Loss Vs High Level Forward Current (Rectangular Current Waveform)

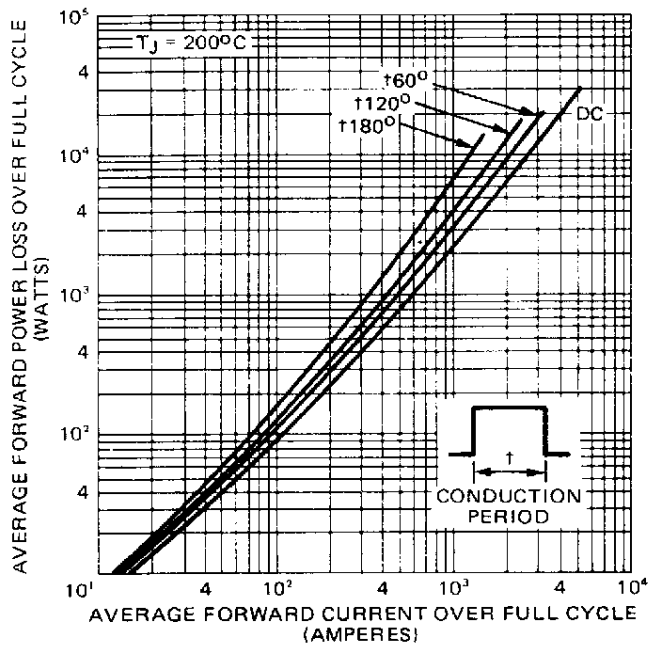


Fig. 9 — Maximum Forward Power Loss Vs High Level Forward Current (Rectangular Current Waveform)



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*Data and specifications subject to change without notice. (1082)*